

A NEW SLED TEST STAND IN THE APS INJECTOR LINAC *

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Abstract

Recently, a new SLED test stand located in the Advanced Photon Source (APS) linac klystron gallery was developed using a spare modulator-klystron system and a recently developed prototype water station. The new test stand will be used to condition, tune, and perform rf measurements on spare SLEDs without interfering with normal daily linac operations. This will allow technical groups to replace a low-performance SLED from one of the operational linac sectors with a fully conditioned SLED. The pre-conditioned SLED is expected to require less conditioning time after being put into operation compared to an unconditioned SLED. As an additional benefit, the prototype water station system developed to replace aging linac water systems can be tested under realistic conditions. In this paper, we describe the test stand design, prototype water station system, and first results using it to condition SLEDs and perform SLED rf measurements.

INTRODUCTION

The Advanced Photon Source [1] injector linac provides excellent availability in supporting storage ring top-up goals. Our operational record is the result of strong preventative maintenance programs, implementation of redundant klystron and source rf gun operation modes, and the use of Procedure Execution Manager [2] tools.

Redundancy is achieved by having a spare klystron and rf gun available, each of which can be quickly switched to replace the standard operational systems in the event of a problem [3]. Additional redundancy is provided by having the ability to achieve 325MeV beam from the linac without one of the last two SLED'd systems that provide rf to the final linac accelerating structures. Recently, the SLED in the final linac system, (L5), developed problems that only allowed it to achieve 20 MW which is less than 15% of the power needed to support beam operations on its own. Even though this low power still allows us to achieve 325MeV, effectively one of our redundant operations modes was no longer available. As a result, the SLED was replaced with a fully conditioned SLED using our new test stand described in this paper.

TEST STAND PREPARATION

A team of engineers and technicians from various support groups were assembled and given the task of assembling a new test stand in the linac using limited money, resources as well as limited material and time.

They understood that the test stand must be capable of providing sufficient rf power to three different areas utilizing two S-band rf waveguide switches. The first rf flow path (mode 1) is a provision for one or more of several possible future uses. The second path (mode 2) is the waveguide component test stand where new S-Band waveguide switches and other waveguide pieces can be conditioned. And finally, the third path (mode 3) will be used for conditioning spare SLAC Energy Doublers or SLEDs [4].

TEST STAND RF SUPPORT

The L6 Test Stand modulator is a conventional PFN-type pulser with a step-up pulse transformer capable of producing DC pulses required for the operation of the Thales' TH2128A and TH2128D S-band klystrons [5]. The klystrons are able to produce pulsed rf power at the frequency of 2,856 MHz.

Parameters of the pulses are:

- Pulse widths (DC): - 5 μ sec;
- Peak voltage: up to 300 kV;
- Peak current: up to 300 Amps;
- Pulse widths (rf): up to 4.5 μ sec;
- Klystron output rf power: up to 30 MW (TH2128A);
- Klystron output rf power: up to 37 MW (TH2128D);
- Repetition rate: up to 30 Hz.

The modulator and low-level rf systems provide very high level of protection against all possible faults in the components under test including excessive vacuum activity and arcing.

PROTOTYPE WATER STATION

The APS linac is divided into five sectors, four of which use individual closed-loop, deionized (DI), temperature-controlled water systems to regulate the temperature of high-power rf components [6].

The rf components in the linac as well as the test stand are made of oxygen-free high-conductivity copper and respond quickly to temperature changes. Changes in water temperature will influence copper components resulting in reflected rf power and, in some cases, beam energy changes.

Because temperature regulation is held to better than $\pm 0.1^\circ\text{F}$ in the linac, we could not take the chance of disrupting the main injector water system to support the L6 test stand for SLED conditioning. In light of that, our mechanical operations and maintenance group designed a prototype water system similar to the ones used in the linac today. Some differences in the prototype (Figure 1) are the overall physical size, which houses a smaller,

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more efficient pump motor, and an improved temperature regulation, which are monitored and controlled by a PLC controller.

Prototype water station requirements:

- Flow rate: 80 gpm
- Temperature stability of: $\pm .05$ degrees F
- System pressure: not to exceed that of the components of the system. < 90 psig
- Deionized water: at > 8 Mohms/cm

The main components of the system consist of a 7.5 hp Grundfos multistage pump, a 14kW heater, a water-to-water heat exchanger, and a three-way mixing valve.



Figure 1: Prototype water skid.

An Allen Bradley Control Logix 5000 PLC is used to achieve the precise temperature control required for rf stability. A standard PID loop is used, which compares the temperature at the RTD located near the mixing valve to the set point selected in the controller. A control signal is then sent via the PLC to the mixing valve to achieve the desired set point. There are two different water temperatures being mixed at the three-way valve: one with heated water and one that has been cooled through the heat exchanger. To improve water quality, a slip-stream of water is bypassed through a mixed-bed resin tank to polish the water through an ion exchange process to achieve the desired resistivity of > 8 Mohms/cm, which is monitored via the PLC as well.

The PLC also handles all of the binary and analog control equipment. Communications with the PLC are achieved through an Ethernet connection that allows an

interface with the EPICS control system at the APS. The connection with EPICS allows us to monitor data remotely and offers the ability for selective control of system operations.

TEST-STAND MECHANICALS

The test stand provides accommodation for mounting various types of SLEDs. A SLED mounting jig shown in Figure 2, was developed and centrally mounted between the rf source and rf load for the test stand (Mode 3) rf conditioning. This apparatus provides flexibility in leveling and aligning of the SLED for easy hook-up of the input and output waveguide. A big time saver!



Figure 2: SLED support jig.

S-BAND SWITCH SYSTEM

The SLED test stand shares use of the sixth klystron in the linac gallery (L6) with a component test stand and provides the opportunity for future use. The most probable of several possible future uses is for L6 to serve as a hot spare for the L4 and L5 klystrons in the same basic way that the L3 klystron serves as a hot spare for the L1 and L2 klystrons in the existing high power S-band switching system [7]. Two reworked commercially available WR340 waveguide switches [8] are used to implement multiple mode functionality for the L6 klystron in essentially the same way as for the L3 klystron. However, the present installation does not use a programmable logic controller (PLC) to implement the switching logic. Instead, a local (only) control panel activates the waveguide switches and steers interlocks via relay logic. A key-controlled switch must be changed from operate mode to switch mode, disabling the klystron drive, before power is made available to the position-selecting push buttons and indirectly to the switch coils. This feature is essentially as described in the Linac 2000 "Testing and Implementation Progress on APS Linear Accelerator High Power S-Band Switching System" [7], but has not been included in the actual implementation of the existing L1-L2-L3, high power S-band switching

